

MSD601-RT1, MSD601-ST1

Preferred Device

NPN General Purpose Amplifier Transistors Surface Mount

Features

- Pb-Free Packages are Available

MAXIMUM RATINGS (T_A = 25°C)

Rating	Symbol	Value	Unit
Collector – Base Voltage	V _{(BR)CBO}	60	Vdc
Collector – Emitter Voltage	V _{(BR)CEO}	50	Vdc
Emitter – Base Voltage	V _{(BR)EBO}	7.0	Vdc
Collector Current – Continuous	I _C	100	mAdc
Collector Current – Peak	I _{C(P)}	200	mAdc

THERMAL CHARACTERISTICS

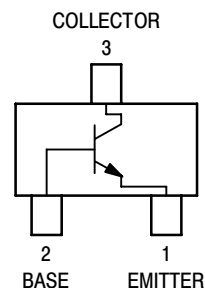
Characteristic	Symbol	Max	Unit
Power Dissipation	P _D	200	mW
Junction Temperature	T _J	150	°C
Storage Temperature	T _{stg}	-55 ~ +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



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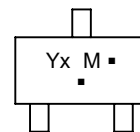
<http://onsemi.com>



MARKING DIAGRAM



SC-59
CASE 318D



- x = R for RT1
S for ST1
 - M = Date Code
 - = Pb-Free Package
- (Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

MSD601–RT1, MSD601–ST1

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

Characteristic	Symbol	Min	Max	Unit
Collector – Emitter Breakdown Voltage (I _C = 2.0 mA _{dc} , I _B = 0)	V _{(BR)CEO}	50	–	V _{dc}
Collector – Base Breakdown Voltage (I _C = 10 μA _{dc} , I _E = 0)	V _{(BR)CBO}	60	–	V _{dc}
Emitter – Base Breakdown Voltage (I _E = 10 μA _{dc} , I _C = 0)	V _{(BR)EBO}	70	–	V _{dc}
Collector – Base Cutoff Current (V _{CB} = 45 V _{dc} , I _E = 0)	I _{CBO}	–	0.1	μA _{dc}
Collector – Emitter Cutoff Current (V _{CE} = 10 V _{dc} , I _B = 0)	I _{CEO}	–	100	nA _{dc}
DC Current Gain (Note 1) (V _{CE} = 10 V _{dc} , I _C = 2.0 mA _{dc}) MSD601–RT1 MSD601–ST1 (V _{CE} = 2.0 V _{dc} , I _C = 100 mA _{dc})	h _{FE1} h _{FE2}	210 290 90	340 460 –	–
Collector – Emitter Saturation Voltage (I _C = 100 mA _{dc} , I _B = 10 mA _{dc})	V _{CE(sat)}	–	0.5	V _{dc}

1. Pulse Test: Pulse Width ≤ 300 μs, D.C. ≤ 2%.

ORDERING INFORMATION

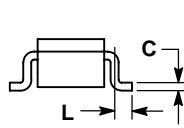
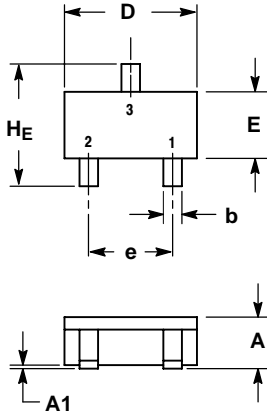
Device	Package	Shipping†
MSD–601RT1	SC–59	3000 Units / Reel
MSD–601RT1G	SC–59 (Pb–Free)	3000 Units / Reel
MSD–601ST1	SC–59	3000 Units / Reel
MSD–601ST1G	SC–59 (Pb–Free)	3000 Units / Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MSD601-RT1, MSD601-ST1

PACKAGE DIMENSIONS

SC-59
CASE 318D-04
ISSUE G

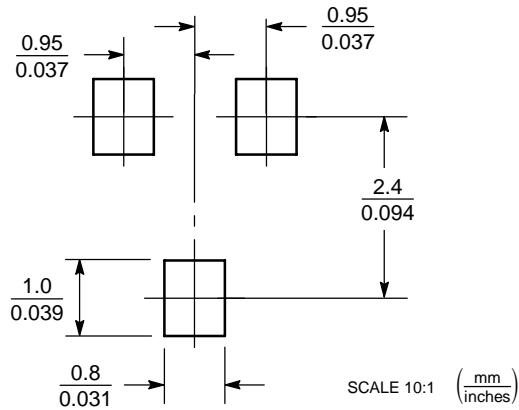


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.00	1.15	1.30	0.039	0.045	0.051
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.35	0.43	0.50	0.014	0.017	0.020
c	0.09	0.14	0.18	0.003	0.005	0.007
D	2.70	2.90	3.10	0.106	0.114	0.122
E	1.30	1.50	1.70	0.051	0.059	0.067
e	1.70	1.90	2.10	0.067	0.075	0.083
L	0.20	0.40	0.60	0.008	0.016	0.024
HE	2.50	2.80	3.00	0.099	0.110	0.118

- STYLE 1:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MSD601-RT1, MSD601-ST1

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